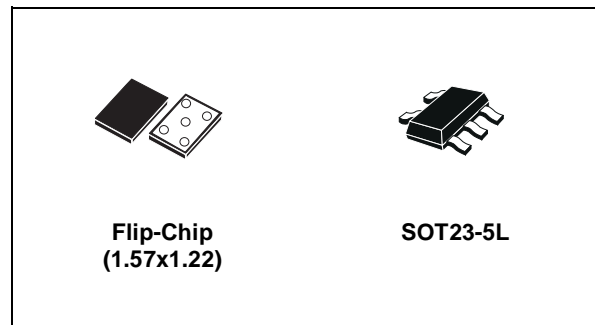




ULTRA LOW DROP-LOW NOISE BICMOS VOLTAGE REGULATORS LOW ESR CAPACITORS COMPATIBLE

- INPUT VOLTAGE FROM 2.5V TO 6V
- STABLE WITH LOW ESR CERAMIC CAPACITORS
- ULTRA LOW DROPOUT VOLTAGE (100mV TYP. AT 150mA LOAD, 0.4mV TYP. AT 1mA LOAD)
- VERY LOW QUIESCENT CURRENT (85 μ A TYP. AT NO LOAD, 170 μ A TYP. AT 150mA LOAD; MAX 1.5 μ A IN OFF MODE)
- GUARANTEED OUTPUT CURRENT UP TO 150mA
- WIDE RANGE OF OUTPUT VOLTAGE: 1.25V; 1.35; 1.5; 1.8V; 2V; 2.1V; 2.2V; 2.4V; 2.5V; 2.6V; 2.7V; 2.8V; 2.85V; 2.9V; 3V; 3.1V; 3.2V; 3.3V; 4.7V; 5V
- FAST TURN-ON TIME: TYP. 200 μ s [$C_{O}=1\mu$ F, $C_{BYP}=10$ nF AND $I_{O}=1$ mA]
- LOGIC-CONTROLLED ELECTRONIC SHUTDOWN
- INTERNAL CURRENT AND THERMAL LIMIT
- OUTPUT LOW NOISE VOLTAGE 30 μ V_{RMS} OVER 10Hz to 100KHz
- S.V.R. OF 60dB AT 1KHz, 50dB AT 10KHz
- TEMPERATURE RANGE: -40°C TO 125°C

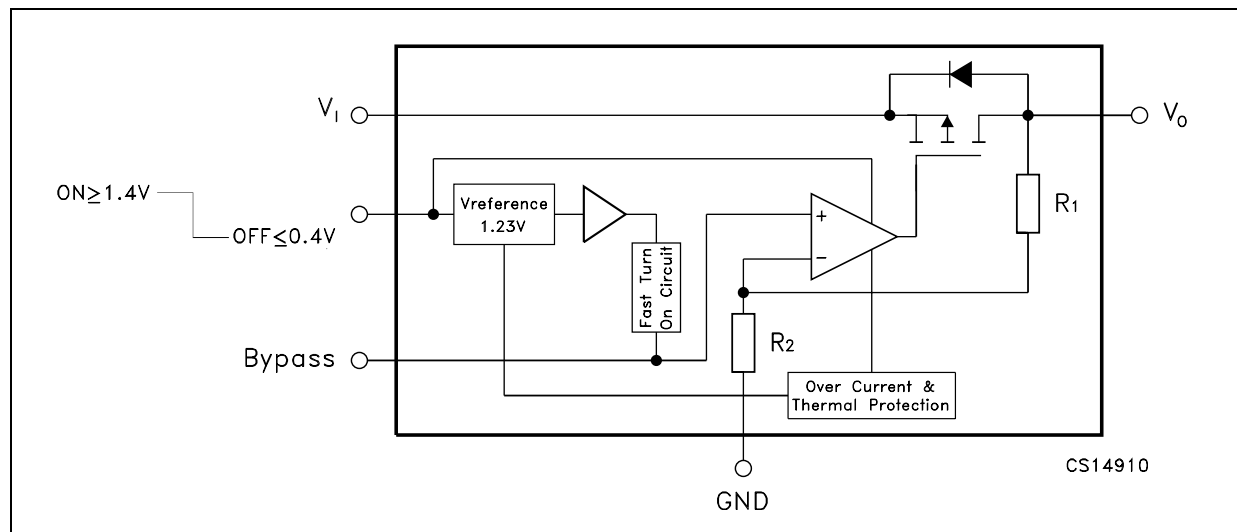


The ultra low drop-voltage, low quiescent current and low noise make it suitable for low power applications and in battery powered systems. Regulator ground current increases only slightly in dropout, further prolonging the battery life. Power supply rejection is better than 60 dB at low frequencies and starts to roll off at 10KHz. High power supply rejection is maintained down to low input voltage levels common to battery operated circuits. Shutdown Logic Control function is available, this means that when the device is used as local regulator, it is possible to put a part of the board in standby, decreasing the total power consumption. The LD3985 is designed to work with low ESR ceramic capacitors. Typical applications are in mobile phone and similar battery powered wireless systems.

DESCRIPTION

The LD3985 provides up to 150mA, from 2.5V to 6V input voltage.

SCHEMATIC DIAGRAM



LD3985 SERIES

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_I	DC Input Voltage	-0.3 to 6 (*)	V
V_O	DC Output Voltage	-0.3 to $V_I+0.3$	V
V_{INH}	INHIBIT Input Voltage	-0.3 to $V_I+0.3$	V
I_O	Output Current	Internally limited	
P_D	Power Dissipation	Internally limited	
T_{STG}	Storage Temperature Range	-65 to 150	°C
T_{OP}	Operating Junction Temperature Range	-40 to 125	°C

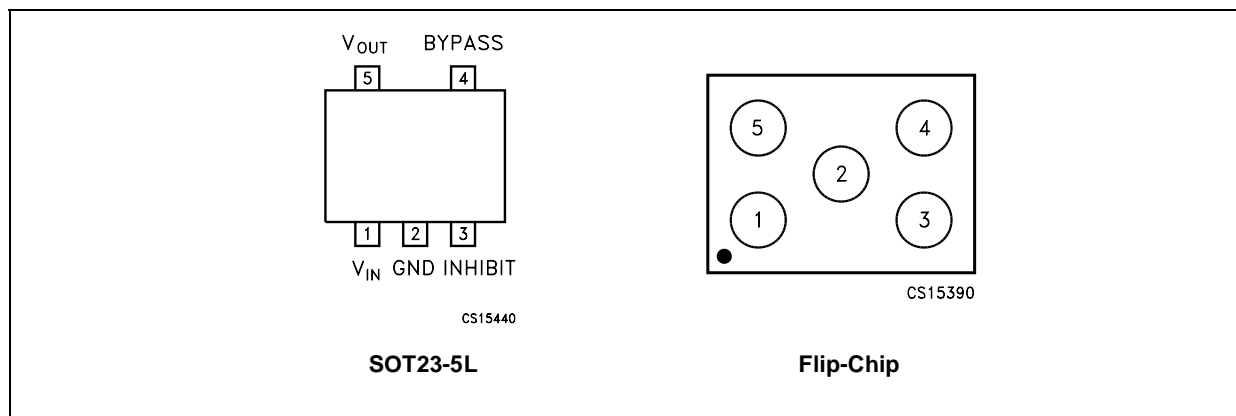
Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(*) The input pin is able to withstand non repetitive spike of 6.5V for 200ms.

THERMAL DATA

Symbol	Parameter	SOT23-5L	Flip-Chip	Unit
$R_{thj-case}$	Thermal Resistance Junction-case	81		°C/W
$R_{thj-amb}$	Thermal Resistance Junction-ambient	255	170	°C/W

CONNECTION DIAGRAM (top view for SOT, top through view for Flip-Chip)



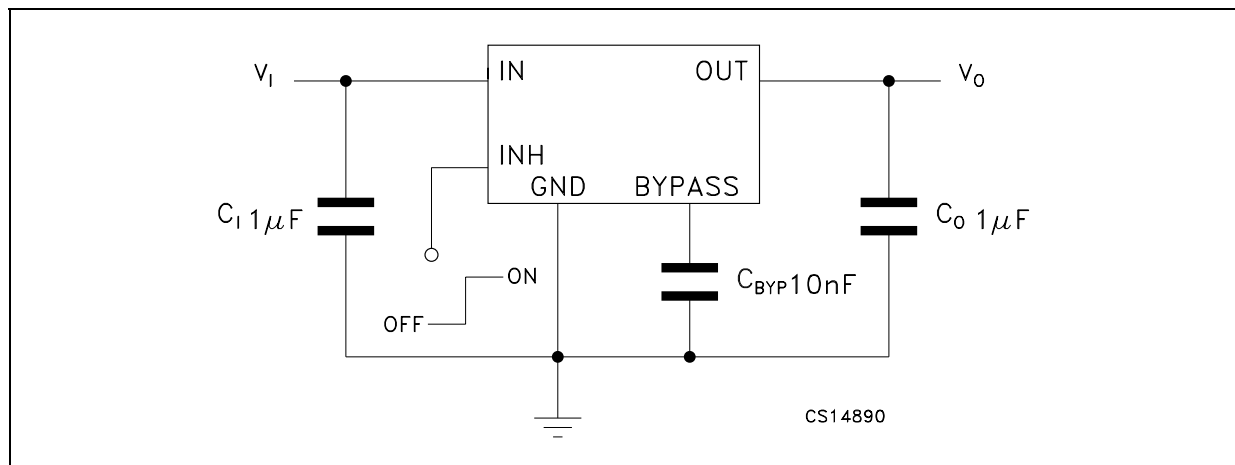
PIN DESCRIPTION

Pin N° SOT23-5L	Pin N° Flip-Chip	Symbol	Name and Function
1	4	V_I	Input Voltage of the LDO
2	2	GND	Common Ground
3	1	V_{INH}	Inhibit Input Voltage: ON MODE when $V_{INH} \geq 1.2V$, OFF MODE when $V_{INH} \leq 0.4V$ (Do not leave floating, not internally pulled down/up)
4	5	BYPASS	Bypass Pin: Connect an external capacitor (usually 10nF) to minimize noise voltage
5	3	V_O	Output Voltage of the LDO

ORDERING CODES

SOT23-5L	Flip-Chip	OUTPUT VOLTAGES
LD3985M125R	LD3985J125R	1.25 V
LD3985M135R	LD3985J135R	1.35 V
LD3985M15R	LD3985J15R	1.5 V
LD3985M18R	LD3985J18R	1.8 V
LD3985M20R	LD3985J20R	2.0 V
LD3985M21R	LD3985J21R	2.1 V
LD3985M22R	LD3985J22R	2.2 V
LD3985M24R	LD3985J24R	2.4 V
LD3985M25R	LD3985J25R	2.5 V
LD3985M26R	LD3985J26R	2.6 V
LD3985M27R	LD3985J27R	2.7 V
LD3985M28R	LD3985J28R	2.8 V
LD3985M285R	LD3985J285R	2.85 V
LD3985M29R	LD3985J29R	2.9 V
LD3985M30R	LD3985J30R	3.0 V
LD3985M31R	LD3985J31R	3.1 V
LD3985M32R	LD3985J32R	3.2 V
LD3985M33R	LD3985J33R	3.3 V
LD3985M47R	LD3985J47R	4.7 V
LD3985M48R	LD3985J48R	4.8 V
LD3985M49R	LD3985J49R	4.9 V
LD3985M50R	LD3985J50R	5.0 V

TYPICAL APPLICATION CIRCUIT



LD3985 SERIES

ELECTRICAL CHARACTERISTICS FOR LD3985 ($T_j = 25^\circ\text{C}$, $V_I = V_{O(NOM)} + 0.5\text{V}$, $C_I = 1\mu\text{F}$, $C_{BYP} = 10\text{nF}$, $I_O = 1\text{mA}$, $V_{INH} = 1.4\text{V}$, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_I	Operating Input Voltage		2.5		6	V
V_O	Output Voltage	$I_O = 1\text{mA}$	-2		2	% of $V_{O(NOM)}$
		$T_J = -40\text{ to }125^\circ\text{C}$	-3		3	
ΔV_O	Line Regulation (Note 1)	$V_I = V_{O(NOM)} + 0.5\text{ to }6\text{V}$, $T_J = -40\text{ to }125^\circ\text{C}$	-0.1		0.1	% / V
		$V_O = 4.7\text{ to }5\text{V}$	-0.19		0.19	
ΔV_O	Load Regulation	$I_O = 1\text{mA to }150\text{mA}$ (for Flip Chip) $T_J = -40\text{ to }125^\circ\text{C}$		0.0004	0.002	% / mA
		$I_O = 1\text{mA to }150\text{mA}$, $T_J = -40\text{ to }125^\circ\text{C}$ (for SOT23-5L)		0.0025	0.005	
ΔV_O	Output AC Line Regulation	$V_I = V_{O(NOM)} + 1\text{V}$, $I_O = 150\text{mA}$, $t_R = t_F = 30\mu\text{s}$		1.5		mV _{PP}
I_Q	Quiescent Current ON MODE: $V_{INH} = 1.2\text{V}$	$I_O = 0$		85		μA
		$I_O = 0$	$T_J = -40\text{ to }125^\circ\text{C}$		150	
		$I_O = 0\text{ to }150\text{mA}$		170		
		$I_O = 0\text{ to }150\text{mA}$	$T_J = -40\text{ to }125^\circ\text{C}$		250	
	OFF MODE: $V_{INH} = 0.4\text{V}$			0.003		
		$T_J = -40\text{ to }125^\circ\text{C}$			1.5	
V_{DROP}	Dropout Voltage (NOTE 1)	$I_O = 1\text{mA}$		0.4		mV
		$I_O = 1\text{mA}$	$T_J = -40\text{ to }125^\circ\text{C}$		2	
		$I_O = 50\text{mA}$		20		
		$I_O = 50\text{mA}$	$T_J = -40\text{ to }125^\circ\text{C}$		35	
		$I_O = 100\text{mA}$		45		
		$I_O = 100\text{mA}$	$T_J = -40\text{ to }125^\circ\text{C}$		70	
		$I_O = 150\text{mA}$		60		
		$I_O = 150\text{mA}$	$T_J = -40\text{ to }125^\circ\text{C}$		100	
I_{SC}	Short Circuit Current	$R_L = 0$		600		mA
SVR	Supply Voltage Rejection	$V_I = V_{O(NOM)} + 0.25\text{V} \pm$ $V_{RIPPLE} = 0.1\text{V}$, $I_O = 50\text{mA}$ $V_{O(NOM)} < 2.5\text{V}$, $V_I = 2.55\text{V}$	$f = 1\text{KHz}$	60		dB
			$f = 10\text{KHz}$	50		
$I_{O(PK)}$	Peak Output Current	$V_O \geq V_{O(NOM)} - 5\%$	300	550		mA
V_{INH}	Inhibit Input Logic Low	$V_I = 2.5\text{V to }6\text{V}$	$T_J = -40\text{ to }125^\circ\text{C}$		0.4	V
	Inhibit Input Logic High			1.2		
I_{INH}	Inhibit Input Current	$V_{INH} = 0.4\text{V}$	$V_I = 6\text{V}$		± 1	nA
eN	Output Noise Voltage	$B_W = 10\text{ Hz to }100\text{ KHz}$	$C_O = 1\mu\text{F}$		30	μV_{RMS}
t_{ON}	Turn On Time (Note 4)	$C_{BYP} = 10\text{ nF}$			200	μs
T_{SHDN}	Thermal Shutdown	Note 5			160	$^\circ\text{C}$
C_O	Output Capacitor	Capacitance (Note 6)		1	22	μF
		ESR		5		5000

Note 1 – For $V_{O(NOM)} < 2\text{V}$, $V_I = 2.5\text{V}$

Note 2 – For $V_{O(NOM)} = 1.25\text{V}$, $V_I = 2.5\text{V}$

Note 3 – Dropout voltage is the input-to-output voltage difference at which the output voltage is 100mV below its nominal value. This specification does not apply for input voltages below 2.5V.

Note 4 – Turn-on time is time measured between the enable input just exceeding V_{INH} High Value and the output voltage just reaching 95% of its nominal value

Note 5 – Typical thermal protection hysteresis is 20°C

Note 6 - The minimum capacitor value is $1\mu\text{F}$, anyway the LD3985 is still stable if the compensation capacitor has a 30% tolerance in all temperature range.

TYPICAL PERFORMANCE CHARACTERISTICS ($T_j = 25^\circ\text{C}$, $V_I = V_{O(\text{NOM})} + 0.5\text{V}$, $C_I = C_O = 1\mu\text{F}$, $C_{\text{BYP}} = 10\text{nF}$, $I_O = 1\text{mA}$, $V_{\text{INH}} = 1.4\text{V}$, unless otherwise specified)

Figure 1 : Output Voltage vs Temperature

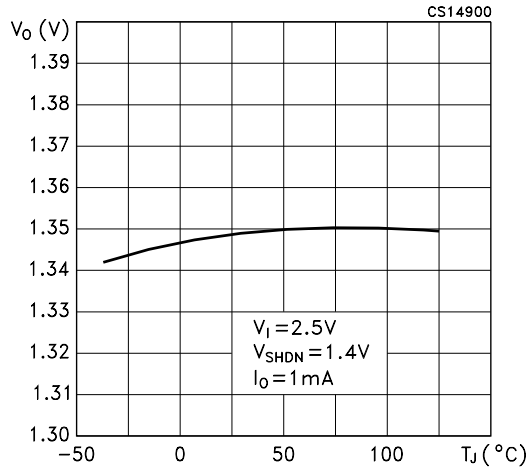


Figure 4 : Shutdown Voltage vs Temperature

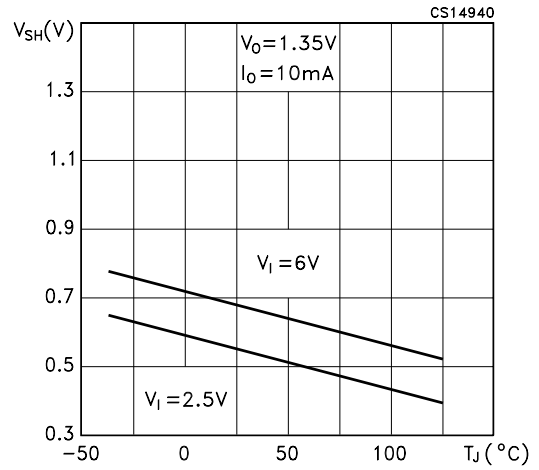


Figure 2 : Output Voltage vs Temperature

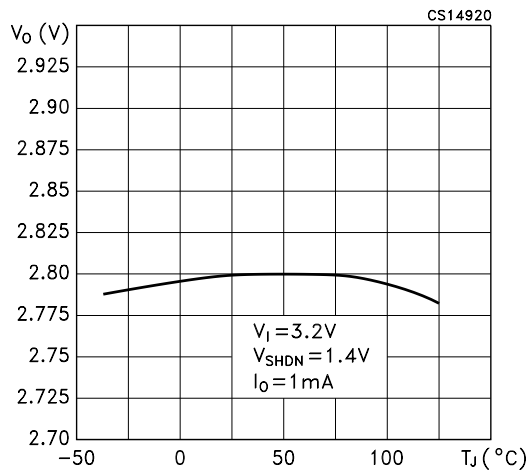


Figure 5 : Shutdown Voltage vs Temperature

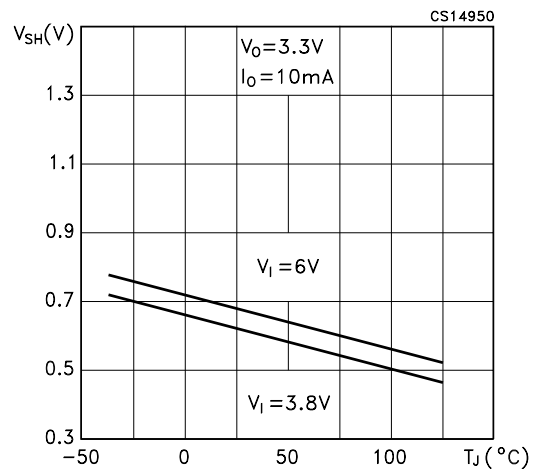


Figure 3 : Output Voltage vs Temperature

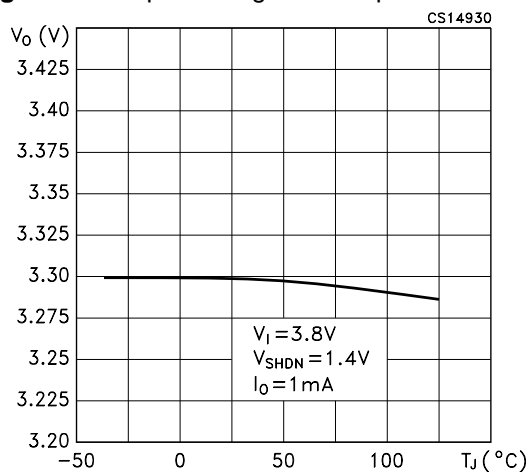


Figure 6 : Line Regulation vs Temperature

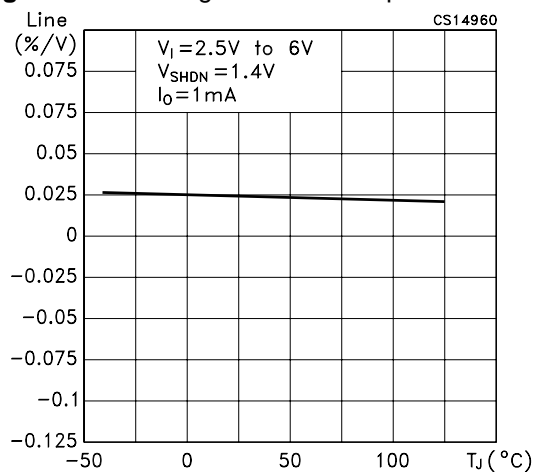


Figure 7 : Line Regulation vs Temperature

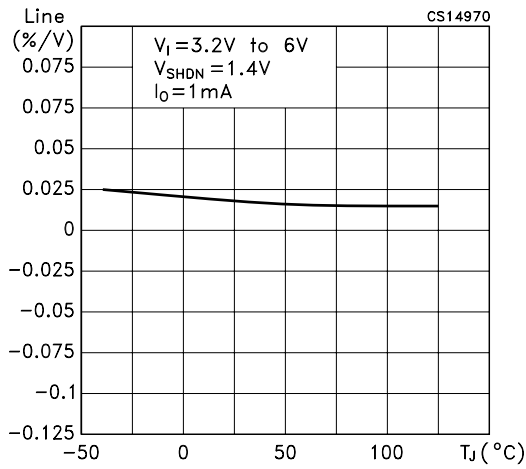


Figure 10 : Load Regulation vs Temperature

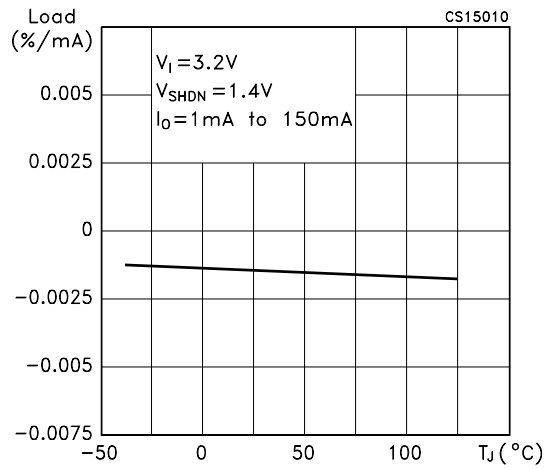


Figure 8 : Line Regulation vs Temperature

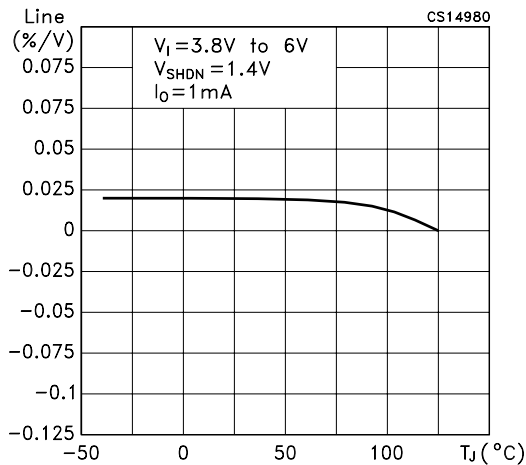


Figure 11 : Load Regulation vs Temperature

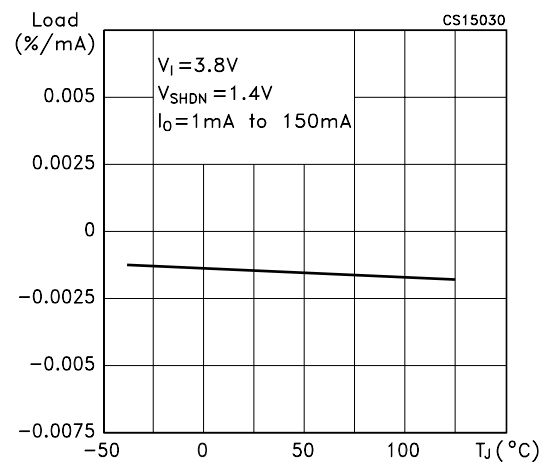


Figure 9 : Load Regulation vs Temperature

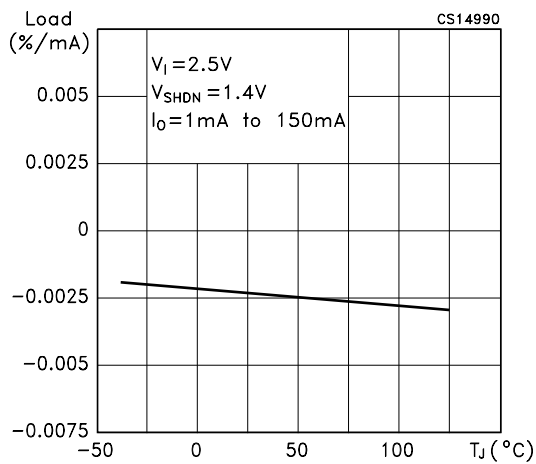


Figure 12 : Quiescent Current vs Temperature

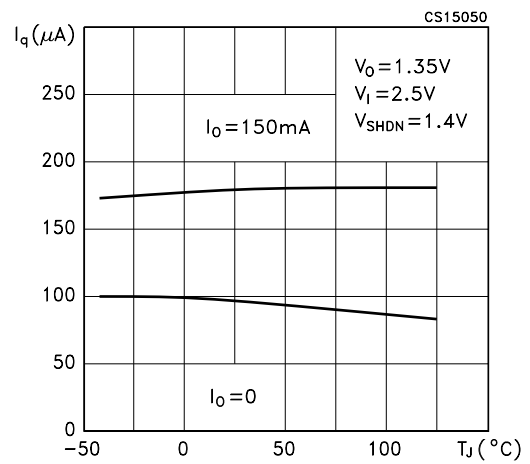


Figure 13 : Quiescent Current vs Temperature

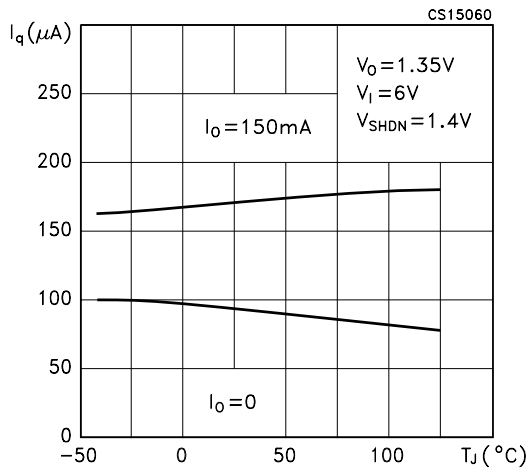


Figure 14 : Quiescent Current vs Temperature

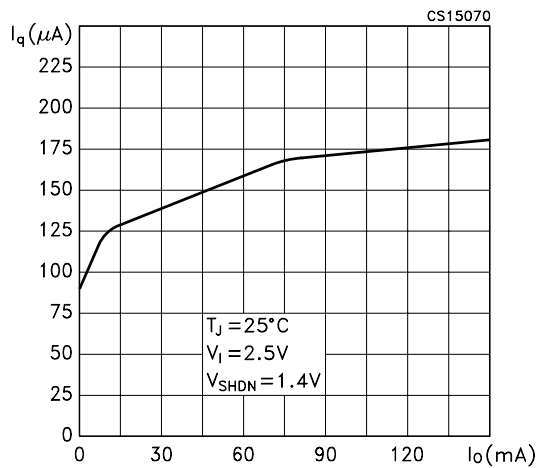


Figure 15 : Supply Voltage Rejection vs Frequency

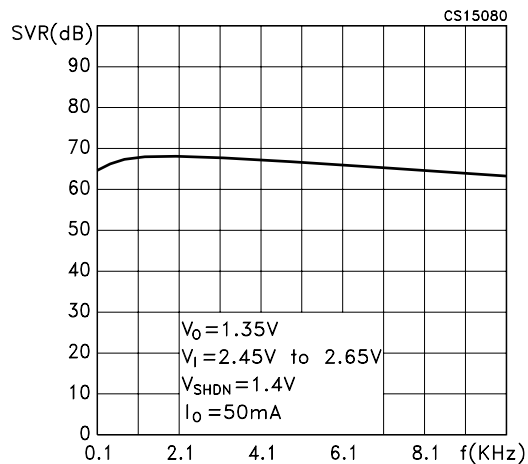


Figure 16 : Load Transient Response

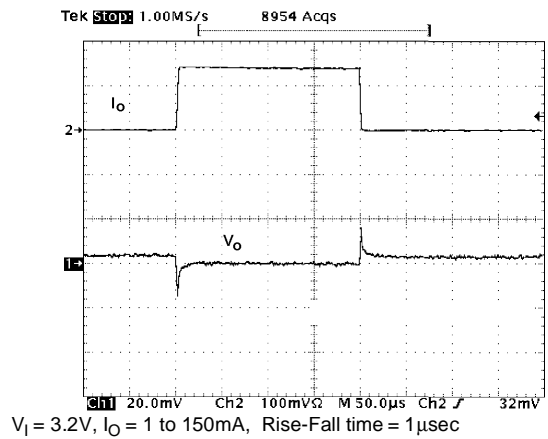


Figure 17 : Line Transient Response

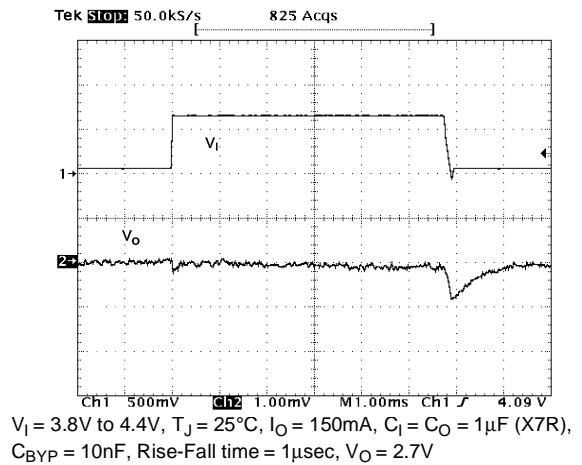


Figure 18 : START-UP

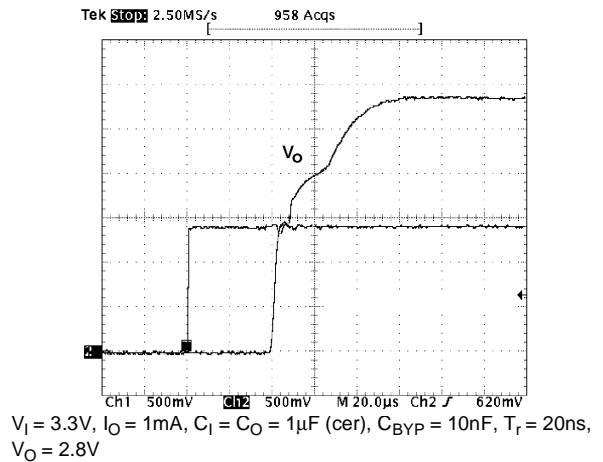
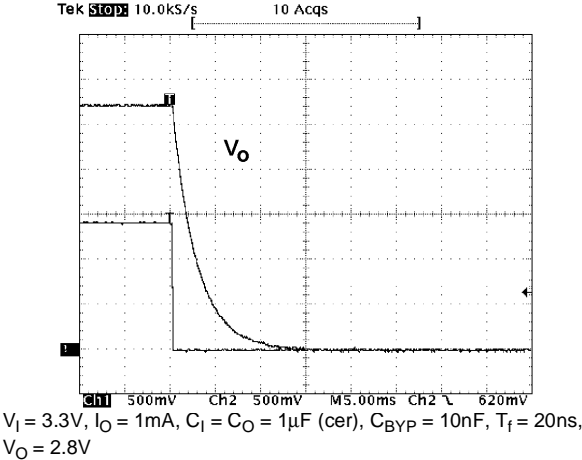
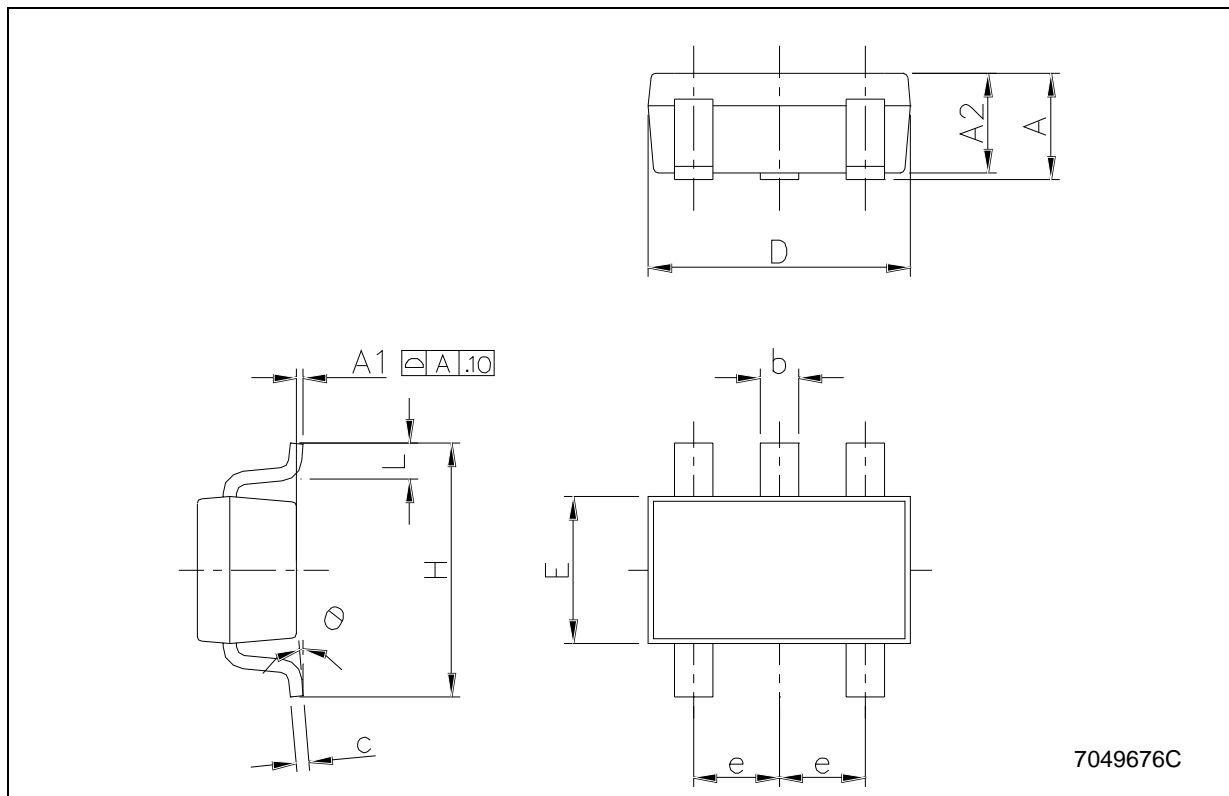


Figure 19 : TURN-OFF



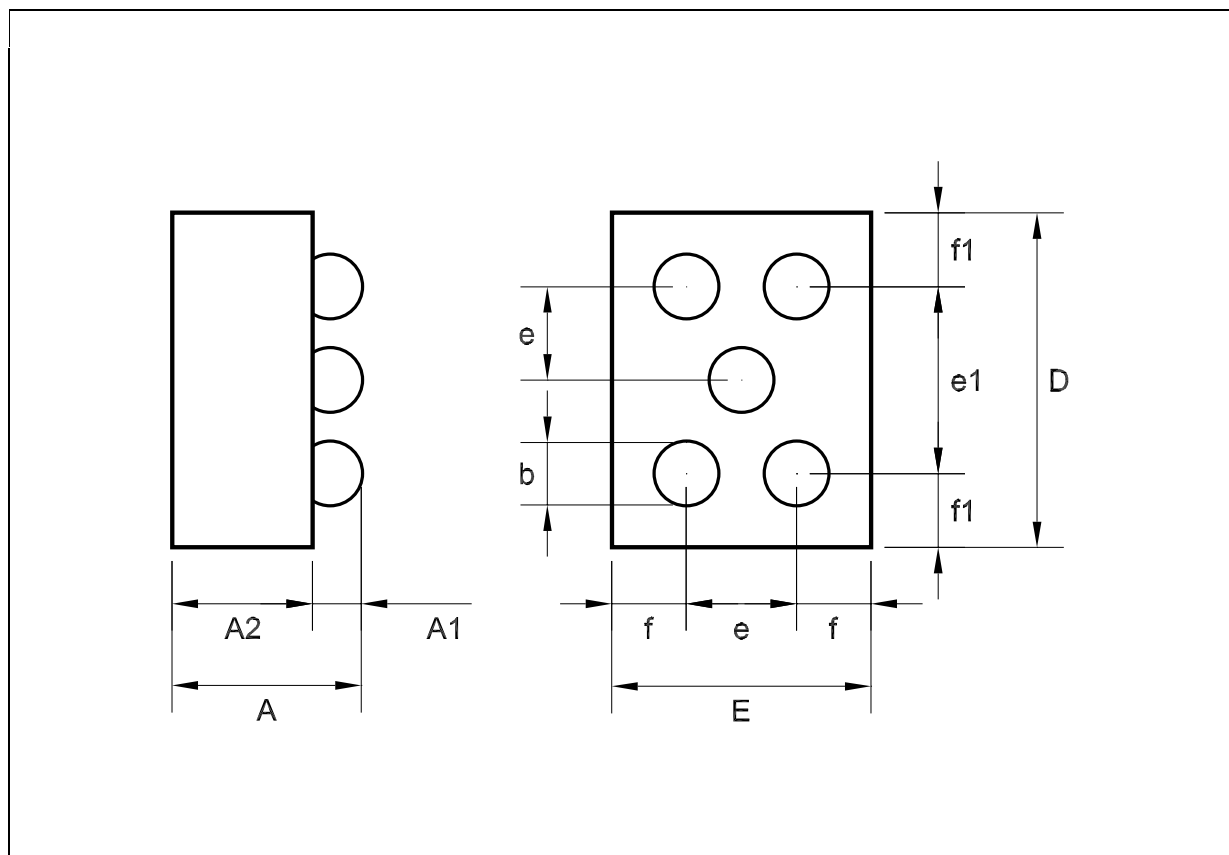
SOT23-5L MECHANICAL DATA

DIM.	mm.			mils		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	0.90		1.45	35.4		57.1
A1	0.00		0.10	0.0		3.9
A2	0.90		1.30	35.4		51.2
b	0.35		0.50	13.7		19.7
C	0.09		0.20	3.5		7.8
D	2.80		3.00	110.2		118.1
E	1.50		1.75	59.0		68.8
e		0.95			37.4	
H	2.60		3.00	102.3		118.1
L	0.10		0.60	3.9		23.6



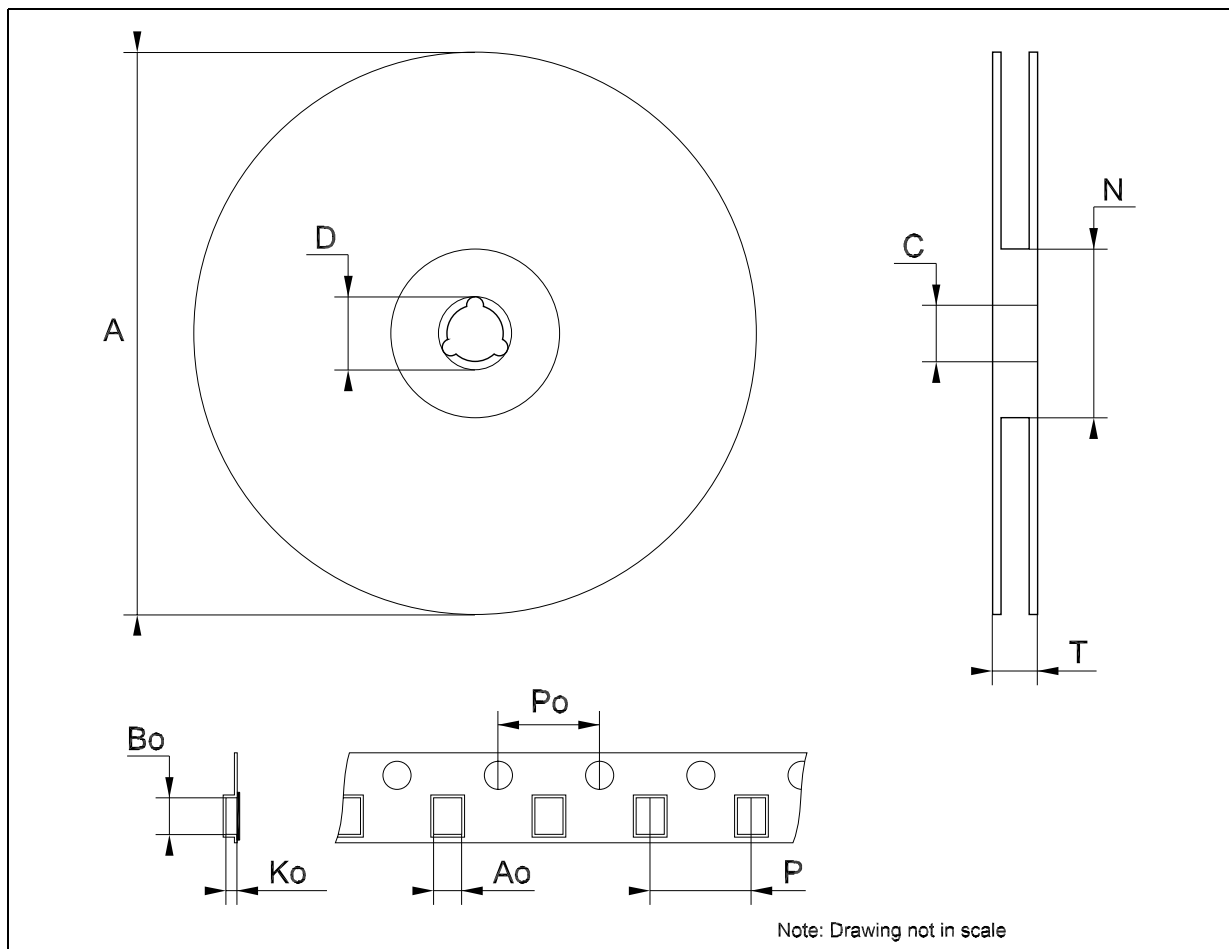
Flip-Chip5 MECHANICAL DATA

DIM.	mm.			mils		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	0.835	0.9	0.965	32.874	35.433	37.992
A1	0.21	0.25	0.29	8.268	9.843	11.417
A2	0.625	0.65	0.675	24.606	25.591	26.575
b	0.265	0.315	0.365	10.433	12.402	14.370
D	1.510	1.540	1.570	59.449	60.630	61.811
E	1.16	1.19	1.22	45.669	46.850	48.031
e	0.45	0.5	0.55	17.717	19.685	21.654
e1	0.816	0.866	0.916	32.126	34.094	36.063
f		0.345			13.583	
f1		0.337			13.268	



Tape & Reel SOT23-xL MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			180			7.086
C	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	60			2.362		
T			14.4			0.567
Ao	3.13	3.23	3.33	0.123	0.127	0.131
Bo	3.07	3.17	3.27	0.120	0.124	0.128
Ko	1.27	1.37	1.47	0.050	0.054	0.058
Po	3.9	4.0	4.1	0.153	0.157	0.161
P	3.9	4.0	4.1	0.153	0.157	0.161



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